



# HIGH EFFICIENCY MONOLITHIC SYNCHRONOUS STEP DOWN REGULATOR

- 2.7V TO 5.5V BATTERY INPUT RANGE
- HIGH EFFICIENCY: UP TO 95%
- INTERNAL SYNCHRONOUS SWITCH
- NO EXTERNAL SCHOTTKY REQUIRED
- EXTREMELY LOW QUIESCENT CURRENT
- 800mA MAX OUTPUT CURRENT
- ADJUSTABLE OUTPUT VOLTAGE FROM 0.6V
- LOW DROP-OUT OPERATION: UP TO100% DUTY CYCLE
- SELECTABLE LOW NOISE/LOW CONSUMPTION MODE AT LIGHT LOAD
- **LOW BATTERY INPUT**
- **LOW BATTERY OUTPUT**
- ±1% OUTPUT VOLTAGE ACCURACY
- CURRENT-MODE CONTROL
- 600kHz SWITCHING FREQUENCY
- EXTERNALLY SYNCHRONIZABLE FROM 500kHz TO 1.4MHz
- OVP
- SHORT CIRCUIT PROTECTION

#### **APPLICATIONS**

- BATTERY-POWERED EQUIPMENTS
- **PORTABLE INSTRUMENTS**
- CELLULAR PHONES
- PDAs AND HAND HELD TERMINALS
- DSC
- GPS



ORDERING NUMBERS: L6925D (Tube)

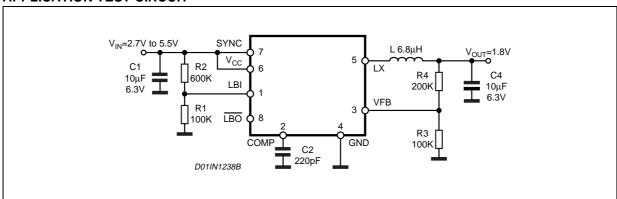
L6925013TR (Tape & Reel)

#### **DESCRIPTION**

The device is dc-dc monolithic regulator specifically designed to provide extremely high efficiency.

The device has on UVLO set at 2.7V cause it is particurarly thought for single Li-ion cell applications. Output voltage can be selected by an external divider down to 0.6V. Duty Cycle can saturate to 100% allowing low drop-out operation. The device is based on a 600kHz fixed-frequency, current mode-architecture. Low Consumption Mode operation can be selected at light load conditions, allowing switching losses to be reduced. L6925D is externally synchronizable with a clock which makes it useful in noisesensitive applications. LBI pin can be used to have a LBO signal when the Battery voltage is lower than a preset value. Other features like, Overvoltage protection, Shortcircuit protection and Thermal Shutdown (150°C) are also present.

#### **APPLICATION TEST CIRCUIT**

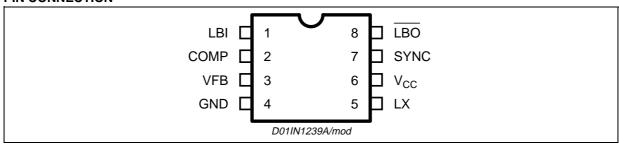


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### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>6</sub>	Input voltage	-0.3 to 6	V
V <sub>5</sub>	Output switching voltage	-1 to V <sub>CC</sub>	V
V <sub>1</sub>	Shutdown	-0.3 to V <sub>CC</sub>	V
V <sub>3</sub>	Feedback voltage	-0.3 to V <sub>CC</sub>	V
V <sub>2</sub>	Analog input voltage	-0.3 to V <sub>CC</sub>	V
P <sub>tot</sub>	Power dissipation at Tamb=70°C	0.45	W
Tj	Junction operating temperature range	-40 to 150	°C
T <sub>stg</sub>	Storage temperature range	-65 to 150	°C
LX Pin	Maximum Withstanding Voltage Range Test Condition: CDF-	±1000	V
Other pins	AEC-Q100-002- "Human Body Model" Acceptance Criteria: "Normal Performance"	±2000	V

# **PIN CONNECTION**



# THERMAL DATA

Symbo	Parameter	Value	Unit
R <sub>th j-am</sub>	Thermal Resistance Junction to Ambient	180	°C/W

## **PIN FUNCTIONS**

N	Name	Description					
1	LBI	Battery low voltage detector input. The internal threshold is set to 0.6V. The external threshold can be adjusted by using an external resistor divider.					
2	COMP	Error amplifier output. Compensate it with a 220pF capacitor					
3	VFB	Error amplifier input. The output voltage can be adjusted by using an external resistor divider connected to this pin ( $V_{FB} = 0.6V$ ).					
4	GND	Ground.					
5	LX	Switch node connection to the inductor.					
6	VCC	Input voltage.					
7	SYNC	This pin allows to select Low Noise/ Low Consumption Mode or to sychronize the device.					
8	LBO	Battery low voltage detector output. If the voltage at the LBI pin drops below the internal thrshold, LBO goes low. The LBO is an open drain output. A pull_up resistor should be connected between the pin and the output voltage					

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# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ , $V_{CC} = 3.6V$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>cc</sub>	Operating input voltage	After Turn On	2.7		5.5	V
V <sub>cc ON</sub>	Turn On threshold			2.8		V
V <sub>cc OFF</sub>	Turn Off threshold			2.65		V
V <sub>cc hys</sub>	Hysteresis			150		mV
Rp	High side Ron	$V_{cc} = 3.6V, I_{IX} = 100mA$		240		mΩ
R <sub>n</sub>	Low side Ron	$V_{cc} = 3.6V$ , $I_{lx} = 100$ mA		215		mΩ
I <sub>lim</sub>	Peak current limit	V <sub>cc</sub> = 3.6V		1.2		Α
	Valley current limit	V <sub>cc</sub> = 3.6V		1.4		А
V <sub>out</sub>	Output voltage range		0.6		Vcc	V
f <sub>osc</sub>	Oscillator frequency			600		KHz
f <sub>sync</sub>	Sync mode clock (*)		500		1400	KHz
DC CHARA	CTERISTICS		_L	I	·L	L
Iq	Quiescent current (low noise mode)	V <sub>sync</sub> = 0V, no load, V <sub>FB</sub> > 0.6V		230		μΑ
	Quiescent current (low cunsumption mode)	$V_{\text{sync}} = V_{\text{cc}}$ , no load, $V_{\text{FB}} > 0.6 \text{V}$		25		μΑ
I <sub>sh</sub>	Shutdown current	V <sub>cc</sub> < 2.7V, V <sub>FB</sub> > 0.6V		0.2		μΑ
I <sub>lx</sub>	LX leakage current (*)	$V_{cc}$ < 2.7V, $V_{LX}$ = $V_{cc}$		1		μΑ
		$V_{cc}$ < 2.7V, $V_{LX}$ = 0V		1		μΑ
ERROR AM	PLIFIER CHARACTERISTICS	1		I .		
$V_{fb}$	Voltage feedback		0.593	0.6	0.607	V
I <sub>fb</sub>	Feedback input current (*)	V <sub>FB</sub> = 0.6V		25		nA
SYNC/MOD	E FUNCTION	1	I	I	·I	
V <sub>sync_H</sub>	Sync mode threshold high				1.3	V
V <sub>sync_L</sub>	Sync mode threshold low		0.5			V
LB SECTIO	N			I	-I	<u> </u>
$V_{LBI}$	LBI Threshold			0.6		V
V <sub>LBO</sub>	LBO Logic Low	$I_{Sink} = 1 \text{mA}, \ V_{CC} = 3.6 \text{V}, \\ V_{LBI} < 0.6 \text{V}$		0.2	0.4	V
I <sub>LK-LBO</sub>	LBO Leakage Current (*)	$V_{\overline{LBO}} = 3.6V, V_{CC} = 3.6V, V_{LBI} > 0.6V$			50	nA
PROTECTIO	DNS		1	<u>I</u>	1	I
HOVP	Hard overvoltage threshold			10		%Vout
	1	i	1	l	1	1

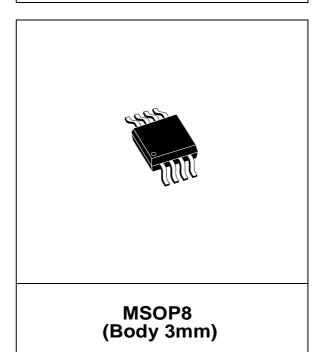
<sup>(\*)</sup> Guaranteed by design

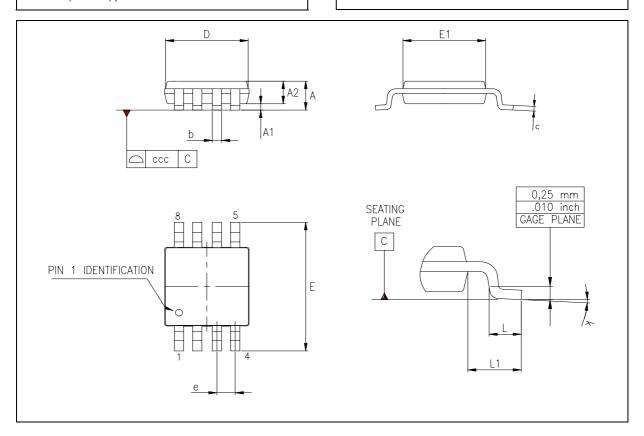
DIM.	mm			inch			
DIWI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.10			0.043	
A1	0.050		0.150	0.002		0.006	
A2	0.750	0.850	0.950	0.03	0.033	0.037	
b	0.250		0.400	0.010		0.016	
С	0.130		0.230	0.005		0.009	
D (1)	2.900	3.000	3.100	0.114	0.118	0.122	
Е	4.650	4.900	5.150	0.183	0.193	0.20	
E1 (1)	2.900	3.000	3.100	0.114	0.118	0.122	
е		0.650			0.026		
L	0.400	0.550	0.700	0.016	0.022	0.028	
L1		0.950			0.037		
k	0° (min.) 6° (max.)						
aaa			0.100			0.004	

Note: 1. D and F does not include mold flash or protrusions.

Mold flash or potrusions shall not exceed 0.15mm (.006inch) per side.

# OUTLINE AND MECHANICAL DATA





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